

Sonic Fast Recovery Diode

		, ,
V_{RRM}	=	600 V
I _{fav}	<i>=</i> 2x	10 A
t _{rr}	=	35 ns

preliminary

High Performance Fast Recovery Diode Low Loss and Soft Recovery **Common Cathode**

Part number

DHG20C600QB



Backside: cathode

20200213b



Features / Advantages:

- Planar passivated chips
- · Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
- Power dissipation within the diode - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- · Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-3P

- Industry standard outline compatible with TO-247
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

IXYS reserves the right to change limits, conditions and dimensions.



preliminary

Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			600	V
V _{RRM}	max. repetitive reverse blocking vo	oltage	$T_{vJ} = 25^{\circ}C$			600	V
I _R	reverse current, drain current	V_{R} = 600 V	$T_{vJ} = 25^{\circ}C$			15	μA
		V_{R} = 600 V	$T_{vJ} = 125^{\circ}C$			1.2	mA
V _F	forward voltage drop	I _F = 10 A	$T_{v_J} = 25^{\circ}C$			2.22	V
		I _F = 20 A				3.12	V
		I _F = 10 A	T _{vJ} = 125°C			2.17	V
		I _F = 20 A				3.27	V
I FAV	average forward current	$T_c = 95^{\circ}C$	$T_{vJ} = 150 ^{\circ}\text{C}$			10	А
		rectangular d = 0.5					
V _{F0}	threshold voltage		$T_{vJ} = 150^{\circ}C$			1.04	V
r _F	slope resistance	s calculation only				104	mΩ
\mathbf{R}_{thJC}	thermal resistance junction to case)				1.8	K/W
\mathbf{R}_{thCH}	thermal resistance case to heatsin	k			0.3		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			70	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}; V_{R} = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			80	Α
C」	junction capacitance	$V_{R} = 400 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		6		pF
I _{RM}	max. reverse recovery current		$T_{VJ} = 25 °C$		4		Α
		$I_F = 10 \text{ A}; V_R = 400 \text{ V}$	T _{vJ} = °C		tbd		Α
t _{rr}	reverse recovery time	I _F = 10 A; V _R = 400 V -di _F /dt = 200 A/μs	$T_{VJ} = 25 \degree C$		35		ns
	J		T _{vJ} = °C		tbd		ns

20200213b



preliminary

Package TO-3P			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal "			50	Α
T _{vJ}	virtual junction temperature		-55		150	°C
T _{op}	operation temperature		-55		125	°C
T _{stg}	storage temperature		-55		150	°C
Weight				5		g
M _D	mounting torque		0.8		1.2	Nm
F _c	mounting force with clip		20		120	Ν





Part description

- D = Diode
- H = Sonic Fast Recovery Diode
- G = extreme fast 20 = Current Rating [A]
- C = Common Cathode
- 600 = Reverse Voltage [V]QB = TO-3P (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DHG20C600QB	DHG20C600QB	Tube	30	503856

Similar Part	Package	Voltage class
DHG20C600PB	TO-220AB (3)	600

Equivalent Circuits for Simulation		* on die level	$T_{VJ} = 150^{\circ}C$	
) <u>R</u> ₀	Fast Diode		
V _{0 max}	threshold voltage	1.04		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	101		mΩ

IXYS reserves the right to change limits, conditions and dimensions.

20200213b



preliminary



Dim.	Millir	neter	Inches	
Dim.	min	max	min	max
Α	4.70	4.90	0.185	0.193
A1	1.30	1.50	0.051	0.059
A2	1.45	1.65	0.057	0.065
b	0.90	1.15	0.035	0.045
b2	1.90	2.20	0.075	0.087
b4	2.90	3.20	0.114	0.126
С	0.55	0.80	0.022	0.031
D	19.80	20.10	0.780	0.791
D1	16.90	17.20	0.665	0.677
Е	15.50	15.80	0.610	0.622
E1	13.50	13.70	0.531	0.539
е	5.45 BSC		0.215 BSC	
L	19.80	20.20	0.780	0.795
L1	3.40	3.60	0.134	0.142
ØΡ	3.20	3.40	0.126	0.134
ØP1	6.90	7.10	0.272	0.280
S	4.90	5.10	0.193	0.201



IXYS reserves the right to change limits, conditions and dimensions.

20200213b